ES52E9B1V-10.000M



ES52E9 B 1 V -10.000M

Control Voltage

1.5Vdc ±1.0Vdc

L Nominal Frequency

10.000MHz

Series -RoHS Compliant (Pb-free) 5mm x 7mm Ceramic SMD 3.3Vdc Clipped Sinewave Stratum 3 TC(VC)XO

Operating Temperature Range -10°C to +60°C

Frequency Stability -±0.28ppm Maximum

ELECTRICAL SPECIFICATIONS

Nominal Frequency	10.000MHz	
Frequency Stability	±0.28ppm Maximum (Measured at Vdd=3.3Vdc and Vc=1.5Vdc)	
Operating Temperature Range	-10°C to +60°C	
Supply Voltage	3.3Vdc ±5%	
Total Holdover Stability	± 0.37 ppm Maximum (Inclusive of Frequency Stability and 24 hours aging)	
Input Current	1.5mA Maximum	
Output Voltage	0.8Vp-p Clipped Sinewave Minimum (External DC-Cut capacitor required, 150pF recommended)	
Total Frequency Tolerance	±4.6ppm Maximum (Inclusive of Frequency Tolerance, Frequency Stability, Vdd (±1%), Load (±5%), solder reflow, and 20 year aging)	
Load Drive Capability	10kOhms // 10pF	
Output Logic Type	Clipped Sinewave	
Control Voltage	1.5Vdc ±1.0Vdc	
Control Voltage Range	0.0Vdc to Vdd	
Frequency Deviation	±5ppm Minimum	
Linearity	5% Maximum	
Transfer Function	Positive Transfer Characteristic	
Input Impedance	100kOhms Minimum	
Phase Noise	-80dBc/Hz at 10Hz Offset, -115dBc/Hz at 100Hz Offset, -135dBc/Hz at 1kHz Offset, and -145dBc/Hz at >=10kHz Offset (Typical Values at 12.800MHz)	
RMS Phase Jitter	1pSec Maximum (Fj = 12kHz to 20MHz)	
Start Up Time	10mSec Maximum	
Storage Temperature Range	-40°C to +125°C	
ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		

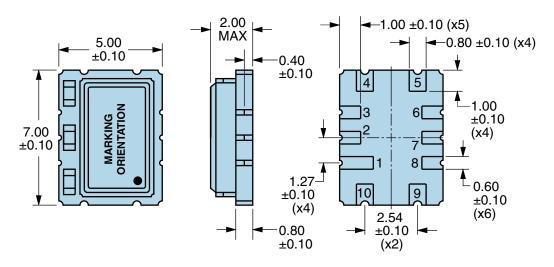
ENVIRONMENTAL & MECHANICAL SPECIFICATIONS

Fine Leak Test	MIL-STD-883, Method 1014 Condition A
Gross Leak Test	MIL-STD-883, Method 1014 Condition C
Mechanical Shock	MIL-STD-202, Method 213 Condition C
Resistance to Soldering Heat	MIL-STD-202, Method 210
Resistance to Solvents	MIL-STD-202, Method 215
Solderability	MIL-STD-883, Method 2003
Temperature Cycling	MIL-STD-883, Method 1010
Vibration	MIL-STD-883, Method 2007 Condition A

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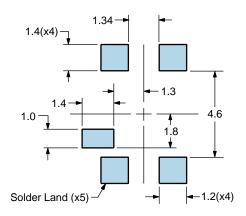
MECHANICAL DIMENSIONS (all dimensions in millimeters)



PIN	CONNECTION
1	Do Not Connect
2	Do Not Connect
3	Do Not Connect
4	Ground
5	Output
6	Do Not Connect
7	Do Not Connect
8	Do Not Connect
9	Supply Voltage
10	Voltage Control
LINE MARKING	
	MARKING
1	EXX.XXX E=Ecliptek Designator XX.XXX=Nominal Frequency in MHz

Suggested Solder Pad Layout

All Dimensions in Millimeters

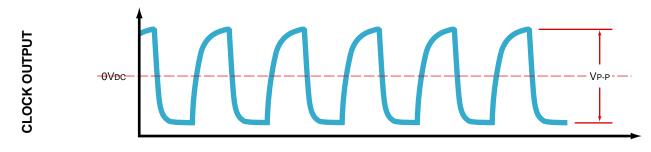


All Tolerances are ±0.1

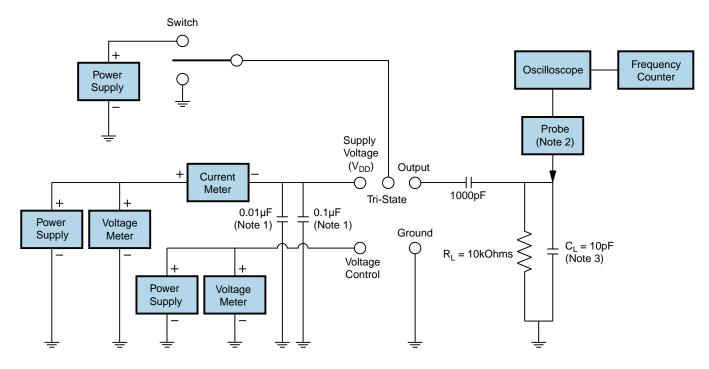
ES52E9B1V-10.000M



OUTPUT WAVEFORM



Test Circuit for Voltage Control Option



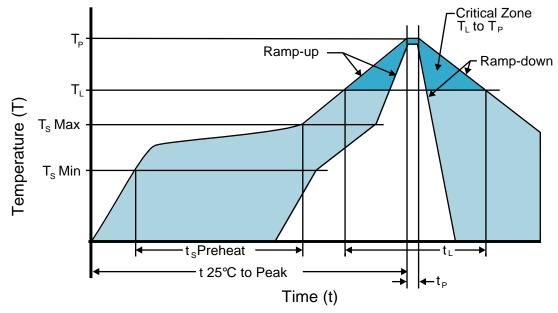
Note 1: An external 0.1 μF low frequency tantalum bypass capacitor in parallel with a 0.01 μF high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value C_L includes sum of all probe and fixture capacitance.



Recommended Solder Reflow Methods



High Temperature Infrared/Convection

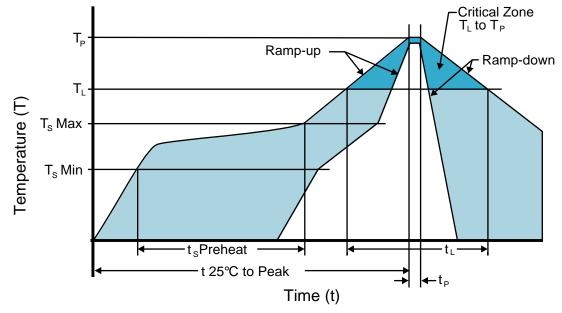
ES52E9B1V-10.000M

T _s MAX to T _L (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	150°C
 Temperature Typical (T_s TYP) 	175°C
 Temperature Maximum (T_s MAX) 	200°C
- Time (t _s MIN)	60 - 180 Seconds
Ramp-up Rate (T⊾ to T _P)	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T _P Target)	250°C +0/-5°C
Time within 5°C of actual peak (t _P)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



Recommended Solder Reflow Methods

ES52E9B1V-10.000M



Low Temperature Infrared/Convection 230°C

T _s MAX to T _L (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	N/A
- Temperature Typical (T _s TYP)	150°C
- Temperature Maximum (T _s MAX)	N/A
- Time (t _s MIN)	30 - 60 Seconds
Ramp-up Rate (T _L to T _P)	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t _L)	200 Seconds Maximum
Peak Temperature (T _P)	230°C Maximum
Target Peak Temperature (T _P Target)	230°C Maximum 2 Times
Time within 5°C of actual peak (t _p)	10 seconds Maximum 2 Times
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.